

Anja Himmerlich

List of Publications by Year in descending order

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8
papers

168
citations

1307594

7
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1588992

8
g-index

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all docs

8
docs citations

8
times ranked

344
citing authors

#	ARTICLE	IF	CITATIONS
1	The Boron–Oxygen (B–O) Defect Complex Induced by Irradiation With 23 GeV Protons in p-Type Epitaxial Silicon Diodes. <i>IEEE Transactions on Nuclear Science</i> , 2022, 69, 576-586.	2.0	8
2	Effects of Potassium Adsorption and Potassium–Water Coadsorption on the Chemical and Electronic Properties of n-Type GaN(0001) Surfaces. <i>Journal of Physical Chemistry C</i> , 2018, 122, 4250-4260.	3.1	6
3	Effects of Plasma Parameter on Morphological and Electrical Properties of Superconducting Nb-N Deposited by MO-PEALD. <i>IEEE Transactions on Applied Superconductivity</i> , 2017, 27, 1-7.	1.7	12
4	Electrochemical lithiation of thin silicon based layers potentiostatically deposited from ionic liquid. <i>Electrochimica Acta</i> , 2015, 168, 403-413.	5.2	42
5	Confirmation of intrinsic electron gap states at nonpolar GaN(1-100) surfaces combining photoelectron and surface optical spectroscopy. <i>Applied Physics Letters</i> , 2014, 104, .	3.3	28
6	Nanometer precise adjustment of the silver shell thickness during automated Au–Ag core–shell nanoparticle synthesis in micro fluid segment sequences. <i>Nanoscale</i> , 2014, 6, 5230.	5.6	33
7	Surface states and electronic structure of polar and nonpolar InN – An <i>in situ</i> photoelectron spectroscopy study. <i>Applied Physics Letters</i> , 2013, 102, .	3.3	21
8	PAMBE growth and <i>in situ</i> characterisation of clean (2 × 2) and (√3 × √3) R30° reconstructed InN(0001) thin films. <i>Physica Status Solidi (B): Basic Research</i> , 2009, 246, 1173-1176.	1.5	18